

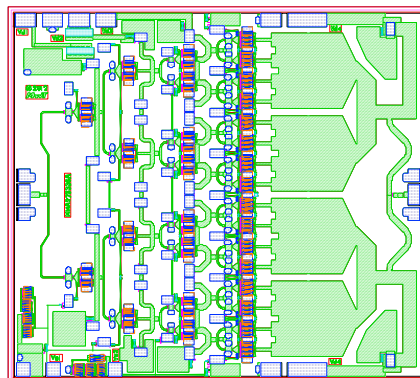
# MMA-273336 27-33GHz 4W MMIC Power Amplifier

## Features:

- Frequency Range: 27 – 33 GHz
- P1dB: +36 dBm
- IM3 Level: -38 dBc @Po=20dBm/tone
- Gain: 22 dB
- Vdd = 6V
- Idsq = 1500 to 2800mA
- Input and Output Fully Matched to 50 Ω

## Applications:

- P2P Radio
- V-sat



Die size: 3.15x2.8x0.05 mm  
124x110x2 mil

## Description:

The MMIC is a high power amplifier MMIC die designed for use in transmitters that operate at frequencies between 27GHz and 33GHz. In the operational frequency band, it provides 36dBm of output power (P-1dB) and 22dB of small-signal gain.

## Absolute Maximum Ratings: (Ta= 25 °C)\*

SYMBOL	PARAMETERS	UNITS	Min.	Max.
Vds	Drain-Source Voltage	V		6.5
Vg	Gate-Source Voltage	V	-2.1	0
Ig	First Gate Current	mA	-17	17
Pd	Power Dissipation	W		24
Pin max	RF Input Power	dBm		20
Toper	Operating Temperature	°C		-40 to +85
Tch	Channel Temperature	°C		+160
Tstg	Storage Temperature	°C		-55 to +150
Tmax	Max. Assembly Temp (20 sec max)	°C		+250

\*Operation of this device above any one of these parameters may cause permanent damage.

**Electrical Specifications:**  *$V_{ds}=6V$ ,  $V_{gs}=-0.85V$ ,  $I_{dsq}=2200mA$ ,  $T_a=25\text{ }^{\circ}C$   $Z_0=50\text{ ohm}$*

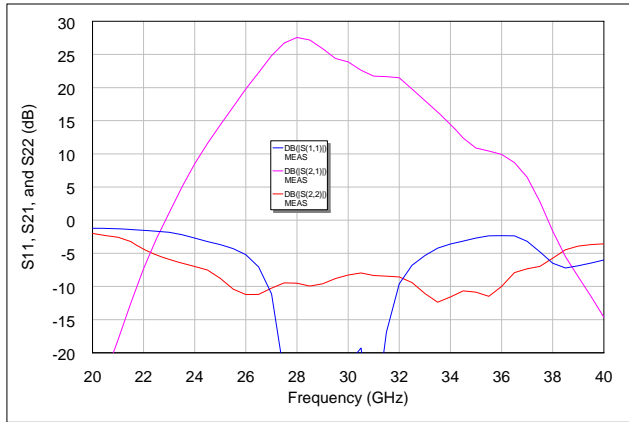
Parameter	Units	Typical Data
Frequency Range	GHz	27-33
Gain (Typ / Min)	dB	22 / 20
Gain Flatness (Typ / Max)	+/-dB	3 / 4
Input RL(Typ/Max)	dB	10/8
Output RL(Typ/Max)	dB	10/8
Output P1dB(Typ/Min)	dBm	35.5/35
Output P3dB(Typ/Min)	dBm	36.5/36
IM3 Level <sup>(1)</sup>	dBc	-36
Thermal Resistance	$^{\circ}C/W$	3.8
Operating Current at P1dB(Typ / Max)	mA	2500 / 3000

(1) Output IP3 is measured with two tones at output power of 20 dBm/tone separated by 20 MHz.

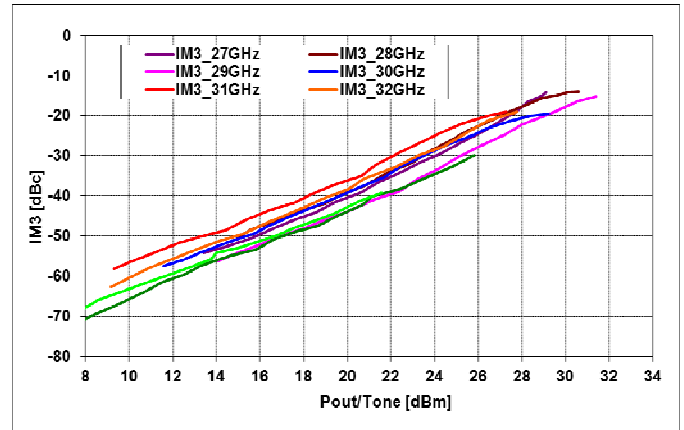
# MMA-273336

## 27-33GHz 4W MMIC Power Amplifier

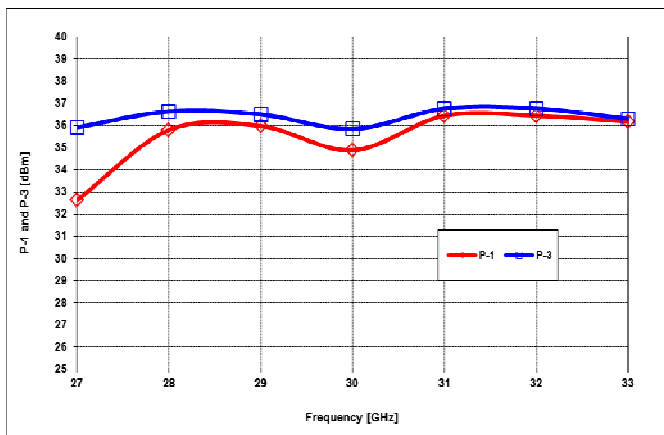
**Typical RF Performance:**  $V_{ds}=6V$ ,  $V_{gsq}=-0.85V$ ,  $I_{dsq}=2200mA$ ,  $Z_0=50\text{ ohm}$ ,  $T_a=25^\circ C$



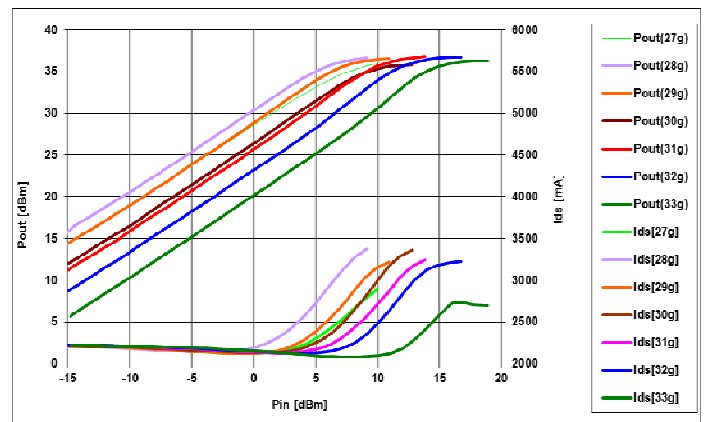
S11, S21, and S22 vs. Frequency



IM3 level [dBc] vs. Output power/tone [dBm]

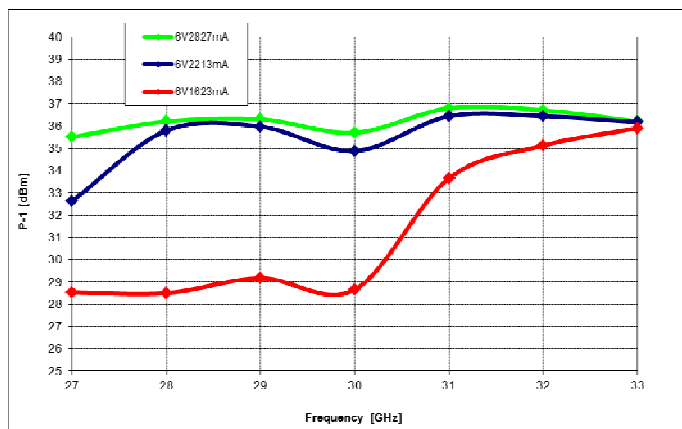


P-1 and P-3 vs. Frequency

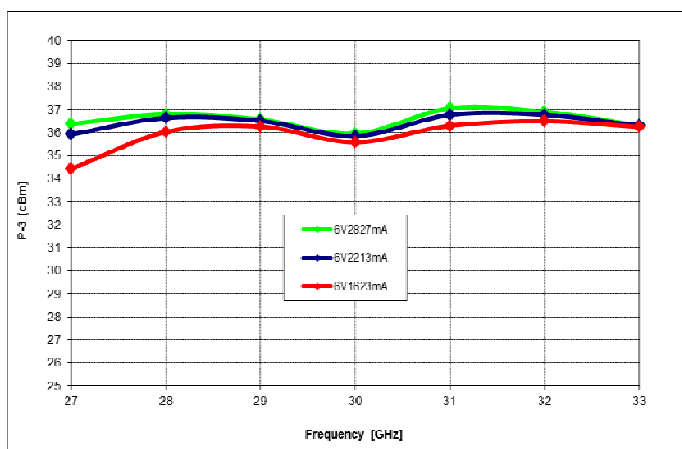


Po(dBm), and Ids(mA) vs. Pin(dBm)

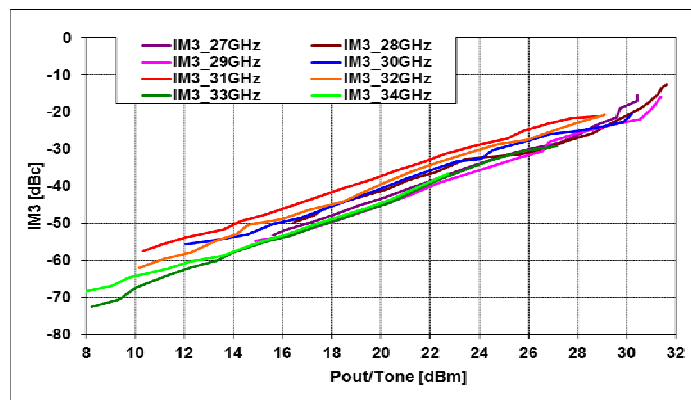
## Typical Bias dependent RF Performance:



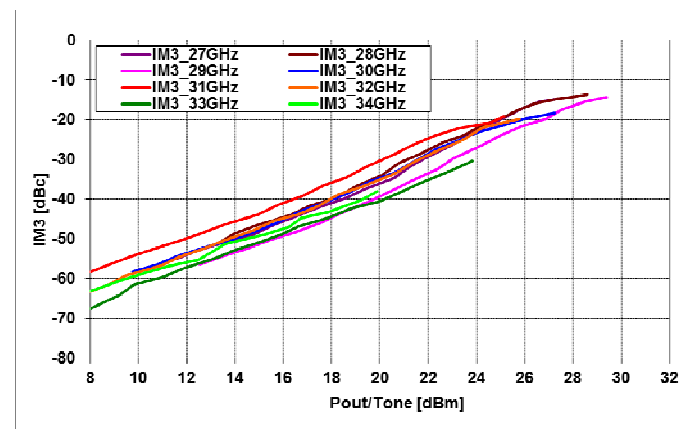
Bias dependent P1 vs. Frequency



Bias dependent P-3 vs. Frequency



IM3 Level [dBc] vs. output power/tone [dBm]  
@Vds=6V, Idsq=2.8A



Pout[dBm], and Ids[mA] vs. Input power [dBm]  
@Vds=6V, Idsq=1.5A

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## Applications

The **MMA273336** MMIC power amplifier is designed for use as a power stage amplifier in microwave transmitters. It is ideally suited for 27 to 33GHz band V-sat transmitter applications requiring excellent saturated output power performance. This amplifier is provided as a bare die format in a Gel-pak.

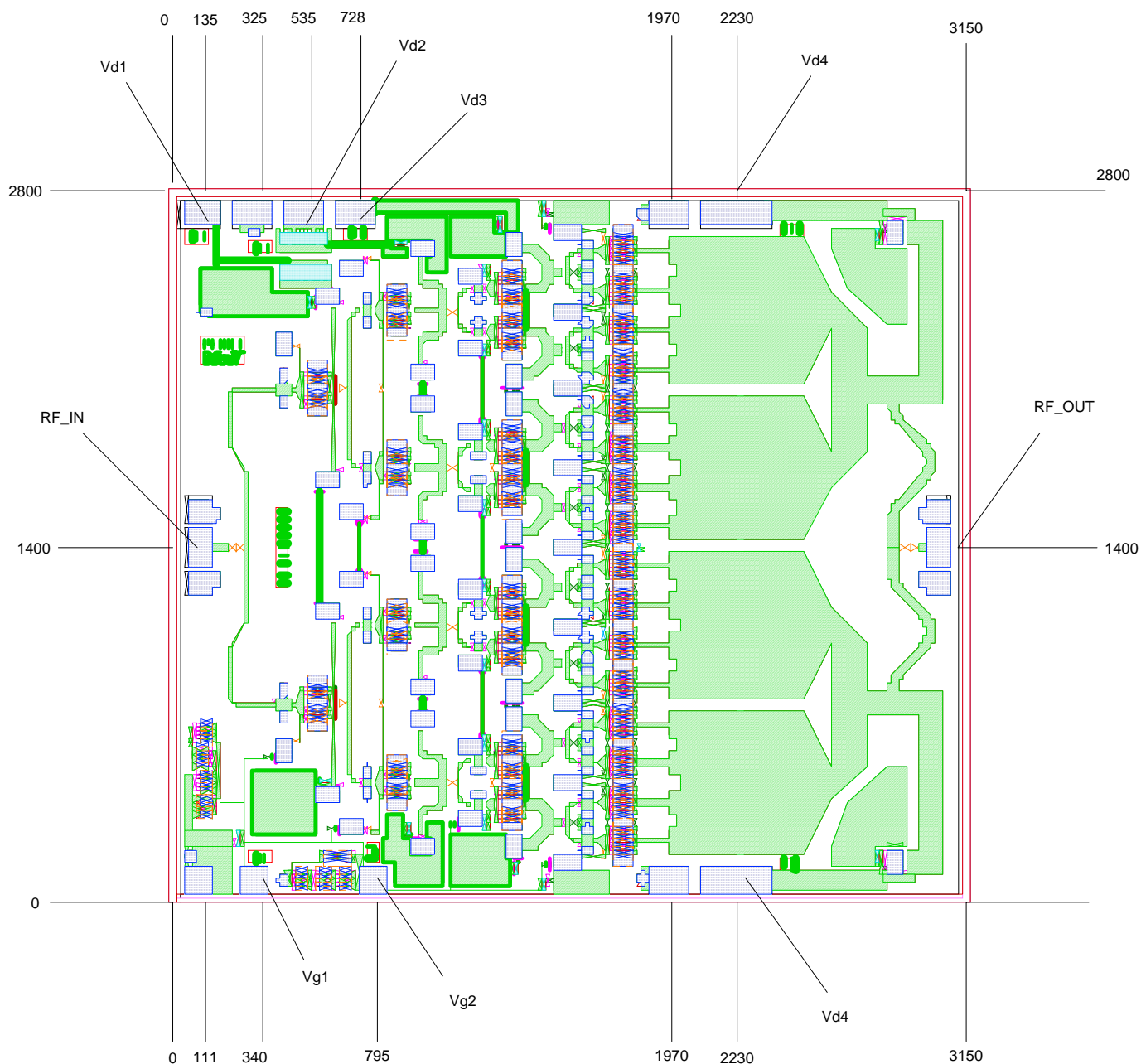
## Biassing and Operation

The recommended bias conditions for best performance for the **MMA273336** are  $V_{DD} = 6.0V$ ,  $I_{dsq} = 2200mA$ . Performance improvements are possible depending on applications. The drain bias voltage range is 5 to 6V and the quiescent drain current biasing range is 1500mA to 2800mA. A single DC gate supply connected to  $V_g$  will bias all the amplifier stages. Muting can be accomplished by setting  $V_g$  to the pinch-off voltage ( $V_{p}=-2V$ ). The gate voltage ( $V_g$ ) should be applied prior to the drain voltages ( $V_{d1}$ ,  $V_{d2}$ ,  $V_{d3}$ ) during power up and removed after the drain voltages during power down. The RF input and output ports are DC decoupled internally. Typical DC supply connection with bi-passing capacitors for the **MMA273336** is shown in following pages.

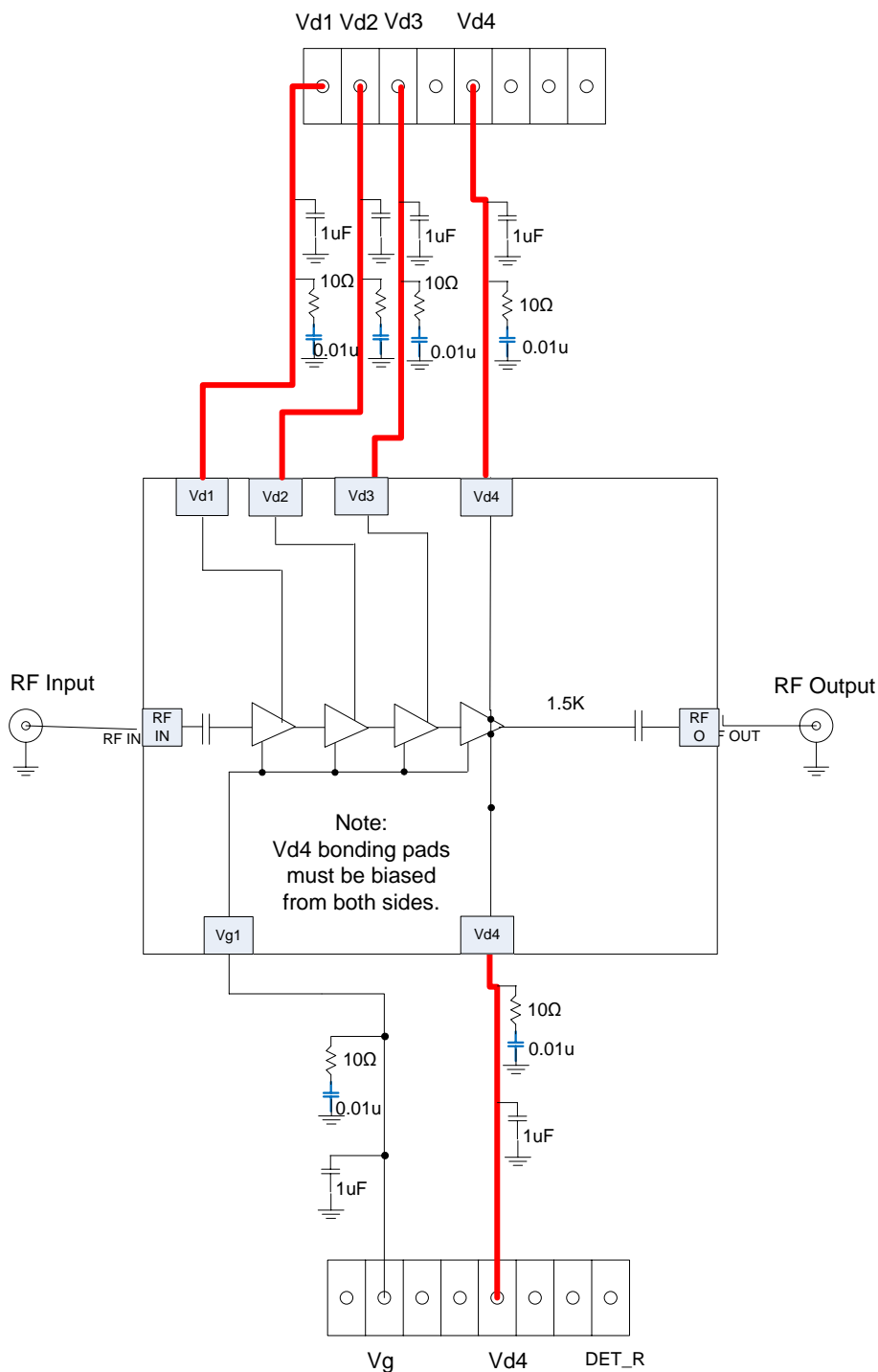
## Assembly Techniques

GaAs MMICs are ESD sensitive. ESD preventive measures must be employed in all aspects of storage, handling, and assembly. MMIC ESD precautions, handling considerations, die attach and bonding methods are critical factors in successful GaAs MMIC performance and reliability.

## Mechanical Information:

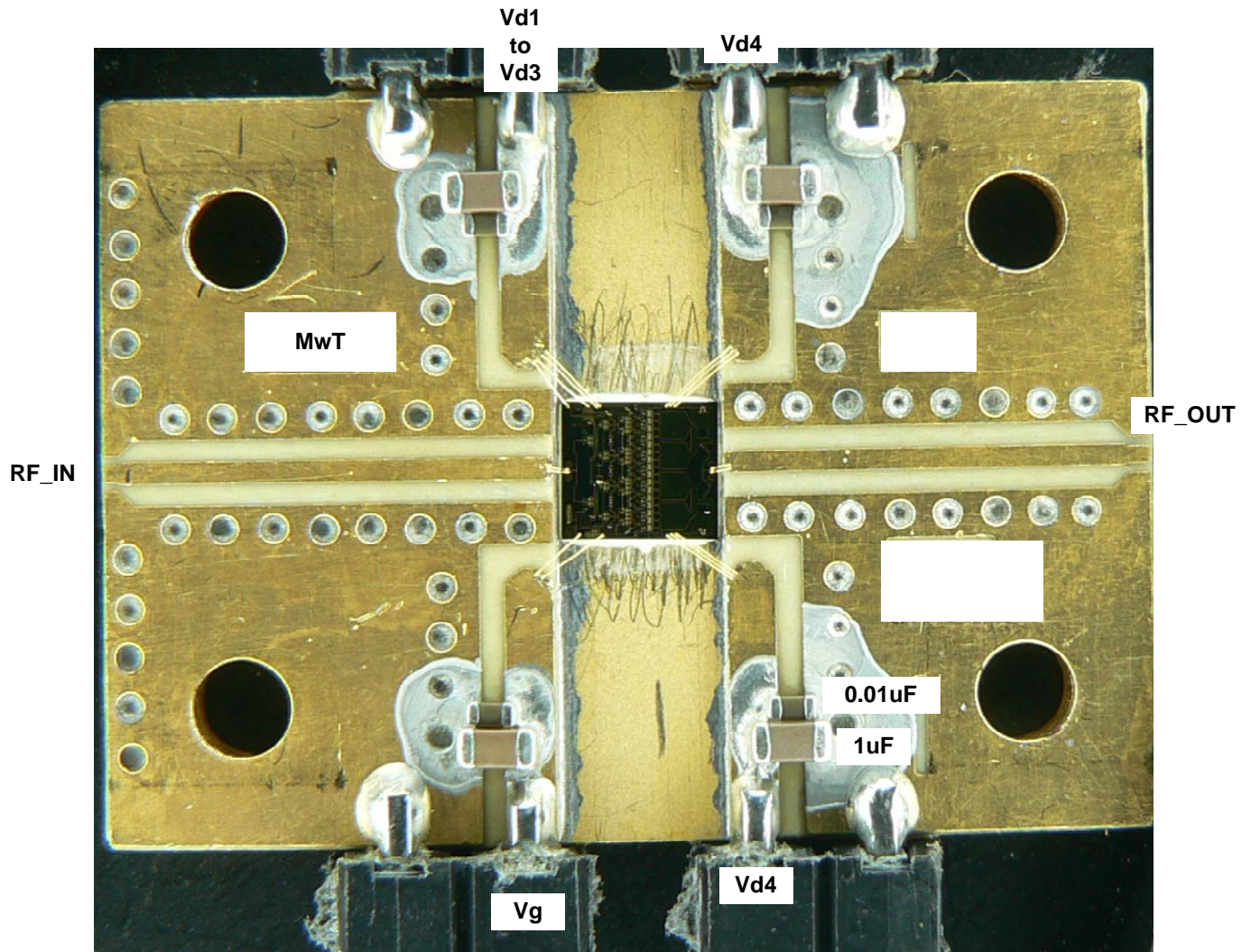


## Application Circuit:



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**Recommended Application Module:**



Contact Information

For additional information please visit [www.cmlmicro.com](http://www.cmlmicro.com) or contact a sales office.

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